

## 800 mA Fixed Low Dropout Positive Regulator

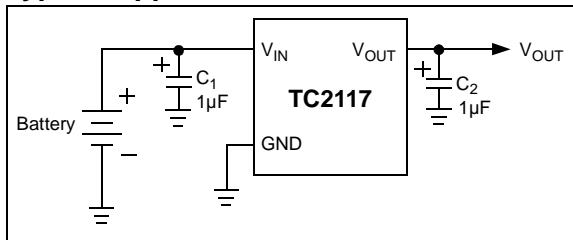
### Features:

- Fixed Output Voltages: 1.8V, 2.5V, 3.0V, 3.3V
- Very Low Dropout Voltage
- Rated 800 mA Output Current
- High Output Voltage Accuracy
- Standard or Custom Output Voltages
- Overcurrent and Overtemperature Protection
- Space Saving SOT-223 Package

### Applications:

- 5V to 3.3V Linear Regulator
- Portable Computers
- Instrumentation
- Battery Operated Systems
- Linear Post-Regulator for SMPS
- Core Voltage Supply for FPGAs, PLDs, CPUs and DSPs

### Typical Application

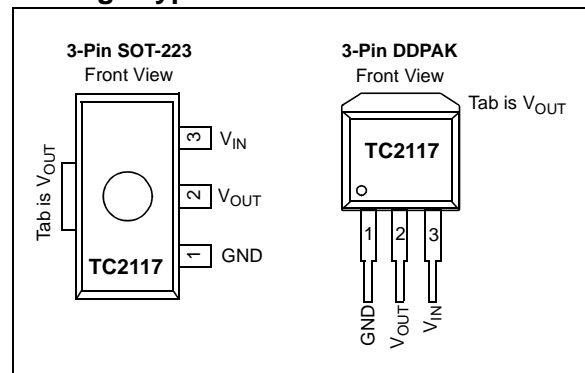


### General Description:

The TC2117 is a fixed, high-accuracy (typically  $\pm 0.5\%$ ) CMOS low dropout regulator. Designed specifically for battery operated systems, the TC2117's CMOS construction eliminates wasted ground current, significantly extending battery life. Total supply current is typically 80  $\mu\text{A}$  at full load (20 to 60 times lower than in bipolar regulators).

TC2117 key features include ultra low noise, very low dropout voltage (typically 450 mV at full load), and fast response to step changes in load. The TC2117 incorporates both overtemperature and overcurrent protection. The TC2117 is stable with an output capacitor of only 1  $\mu\text{F}$  and has a maximum output current of 800 mA. This device is available in 3-Pin SOT-223 and 3-Pin DDPAK packages.

### Package Types



# TC2117

## 1.0 ELECTRICAL CHARACTERISTICS

### Absolute Maximum Ratings†

Input Voltage .....	6.5V
Output Voltage.....	(V <sub>SS</sub> - 0.3) to (V <sub>IN</sub> + 0.3V)
Power Dissipation.....	Internally Limited ( <b>Note 7</b> )
Maximum Voltage on Any Pin .....	V <sub>IN</sub> +0.3V to -0.3V
Operating Temperature .....	-40°C < T <sub>J</sub> < +125°C
Storage temperature .....	-65°C to +150°C

† **Notice:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

### DC CHARACTERISTICS

<b>Electrical Specifications:</b> Unless otherwise indicated, V <sub>IN</sub> = V <sub>R</sub> + 1.5V, ( <b>Note 1</b> ), I <sub>L</sub> = 100 μA, C <sub>L</sub> = 3.3 μF, T <sub>A</sub> = +25°C. <b>Boldface</b> type specifications apply for junction temperatures of -40°C to +125°C.						
Parameters	Sym	Min	Typ	Max	Units	Conditions
Input Operating Voltage	V <sub>IN</sub>	<b>2.7</b>	—	<b>6.0</b>	V	<b>Note 2</b>
Maximum Output Current	I <sub>OUTMAX</sub>	<b>800</b>	—	—	mA	
Output Voltage	V <sub>OUT</sub>	<b>V<sub>R</sub> - 2.5%</b>	V <sub>R</sub> ± 0.5%	<b>V<sub>R</sub> + 2.5%</b>	V	V <sub>R</sub> ≥ 2.5V
		<b>V<sub>R</sub> - 2%</b>	V <sub>R</sub> ± 0.5%	<b>V<sub>R</sub> + 3%</b>		V <sub>R</sub> = 1.8V
V <sub>OUT</sub> Temperature Coefficient	ΔV <sub>OUT</sub> /ΔT	—	40	—	ppm/°C	<b>Note 3</b>
Line Regulation	ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>	—	0.007	<b>0.35</b>	%	(V <sub>R</sub> + 1V) ≤ V <sub>IN</sub> ≤ 6V
Load Regulation ( <b>Note 4</b> )	ΔV <sub>OUT</sub> /V <sub>OUT</sub>	<b>-0.01</b>	0.002	0	%/mA	I <sub>L</sub> = 0.1 mA to I <sub>OUTMAX</sub>
Dropout Voltage ( <b>Note 5</b> )	V <sub>IN</sub> -V <sub>OUT</sub>	—	20	<b>30</b>	mV	V <sub>R</sub> ≥ 2.5V, I <sub>L</sub> = 100 μA
		—	50	<b>160</b>		I <sub>L</sub> = 100 mA
		—	150	<b>480</b>		I <sub>L</sub> = 300 mA
		—	260	<b>800</b>		I <sub>L</sub> = 500 mA
		—	450	<b>1300</b>		I <sub>L</sub> = 800 mA
		—	1000	<b>1200</b>		V <sub>R</sub> = 1.8V, I <sub>L</sub> = 500 mA
		—	1200	<b>1400</b>		I <sub>L</sub> = 800 mA
Supply Current	I <sub>DD</sub>	—	80	<b>130</b>	μA	$\overline{\text{SHDN}} = V_{IH}, I_L = 0$
Power Supply Rejection Ratio	PSRR	—	55	—	db	F ≤ 1 kHz
Output Short Circuit Current	I <sub>OUTSC</sub>	—	1200	—	mA	V <sub>OUT</sub> = 0V
Thermal Regulation	ΔV <sub>OUT</sub> /ΔP <sub>D</sub>	—	0.04	—	V/W	<b>Note 6</b>
Output Noise	eN	—	300	—	nV/√Hz	I <sub>L</sub> = 100 mA, F = 10 kHz

- Note 1:** V<sub>R</sub> is the regulator output voltage setting.
- 2:** The minimum V<sub>IN</sub> has to justify the conditions: V<sub>IN</sub> ≥ V<sub>R</sub> + V<sub>DROPOUT</sub> and V<sub>IN</sub> ≥ 2.7V for I<sub>L</sub> = 0.1 mA to I<sub>OUTMAX</sub>.
- 3:**
- $$TCV_{OUT} = \frac{(V_{OUTMAX} - V_{OUTMIN}) - 10^6}{V_{OUT} \times \Delta T}$$
- 4:** Regulation is measured at a constant junction temperature using low duty cycle pulse testing. Load regulation is tested over a load range from 0.1 mA to the maximum specified output current. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
- 5:** Dropout voltage is defined as the input-to-output differential at which the output voltage drops 2% below its nominal value measured at a 1.5V differential.
- 6:** Thermal regulation is defined as the change in output voltage at a time T after a change in power dissipation is applied, excluding load or line regulation effects. Specifications are for a current pulse equal to I<sub>LMAX</sub> at V<sub>IN</sub> = 6V for T = 10 ms.
- 7:** The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction-to-air (i.e., T<sub>A</sub>, T<sub>J</sub>, θ<sub>JA</sub>). Exceeding the maximum allowable power dissipation causes the device to initiate thermal shutdown. Please see **Section 4.2 "Thermal Considerations"** for more details.

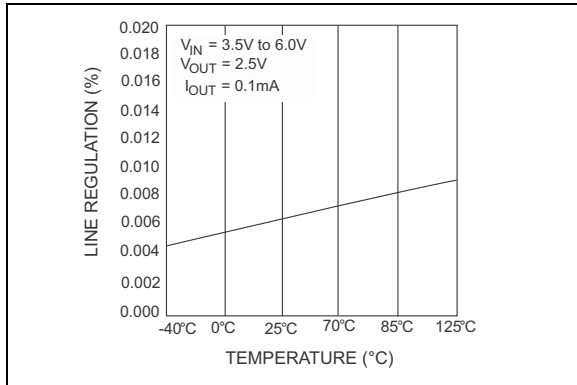
## TEMPERATURE CHARACTERISTICS

<b>Electrical Specifications:</b> Unless otherwise indicated, $V_{IN} = V_R + 1.5V$ , $I_L = 100 \mu A$ , $C_L = 3.3 \mu F$ , $\overline{SHDN} > V_{IH}$ , $T_A = +25^\circ C$ .						
Parameters	Sym	Min	Typ	Max	Units	Conditions
<b>Temperature Ranges</b>						
Specified Temperature Range	$T_A$	-40	—	+125	$^\circ C$	(Note 1)
Operating Temperature Range	$T_J$	-40	—	+125	$^\circ C$	
Storage Temperature Range	$T_A$	-65	—	+150	$^\circ C$	
<b>Thermal Package Resistances</b>						
Thermal Resistance, 3L-SOT-223	$\theta_{JA}$	—	59	—	$^\circ C/W$	
Thermal Resistance, 3L-DDPAK	$\theta_{JA}$	—	71	—	$^\circ C/W$	

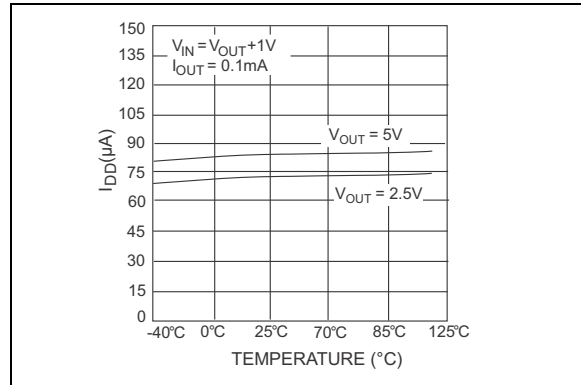
**Note 1:** Operation in this range must not cause  $T_J$  to exceed Maximum Junction Temperature (+125 $^\circ C$ ).

## 2.0 TYPICAL PERFORMANCE CURVES

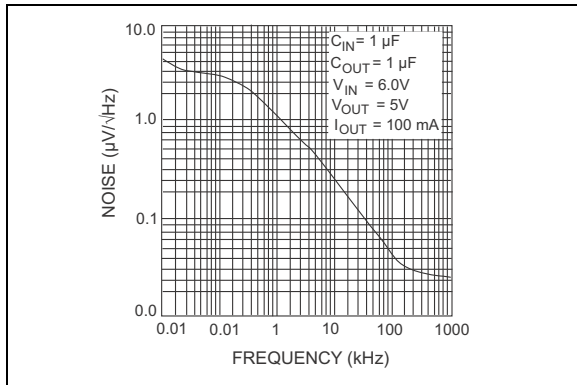
**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.



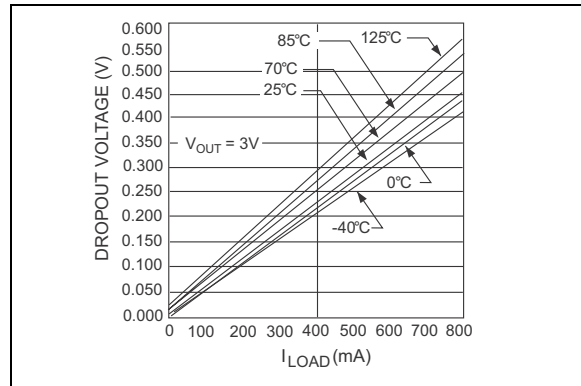
**FIGURE 2-1:** Line Regulation vs. Temperature.



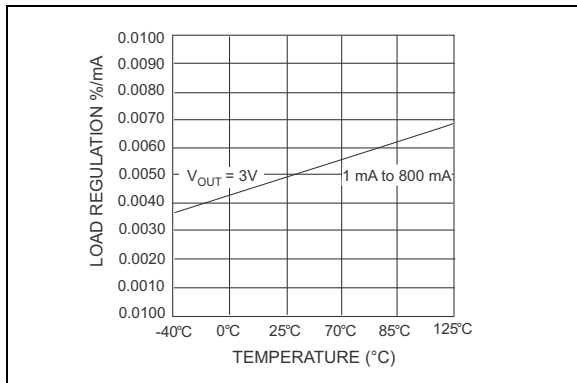
**FIGURE 2-4:**  $I_{DD}$  vs. Temperature.



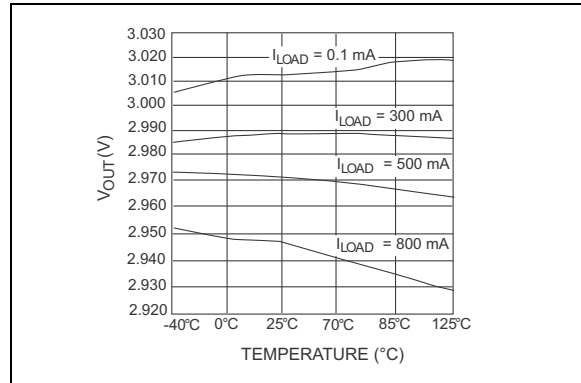
**FIGURE 2-2:** Output Noise vs. Frequency.



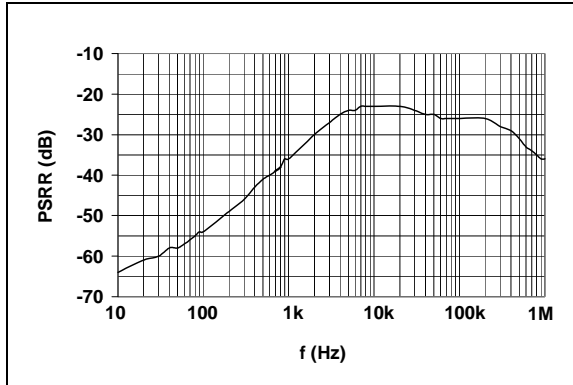
**FIGURE 2-5:** Dropout Voltage vs.  $I_{LOAD}$ .



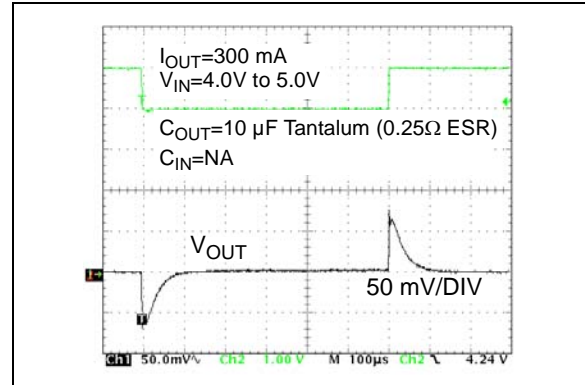
**FIGURE 2-3:** Load Regulation vs. Temperature.



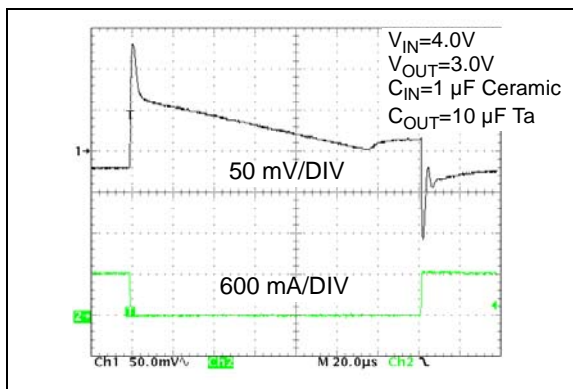
**FIGURE 2-6:** 3.0V  $V_{OUT}$  vs. Temperature.



**FIGURE 2-7:** Power Supply Rejection Ratio.



**FIGURE 2-9:** Line Step Response



**FIGURE 2-8:** Load Step Response.

## 3.0 PIN DESCRIPTIONS

The descriptions for the pins are listed in [Table 3-1](#).

**TABLE 3-1: PIN FUNCTION TABLE**

Pin No. (3-Pin SOT-223) (3-Pin DDPAK)	Symbol	Description
1	GND	Ground Terminal.
2	$V_{OUT}$	Regulated output voltage.
3	$V_{IN}$	Unregulated Supply input.

### 3.1 Ground (GND)

Ground terminal.

### 3.2 Regulated Output Voltage ( $V_{OUT}$ )

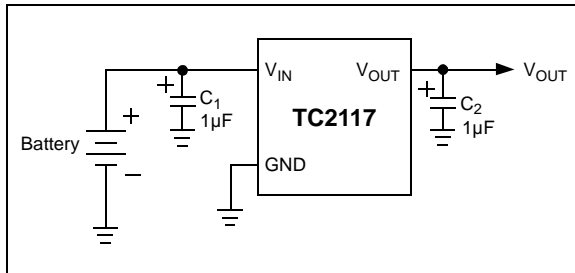
Regulated voltage output.

### 3.3 Unregulated Supply ( $V_{IN}$ )

Unregulated supply input.

## 4.0 DETAILED DESCRIPTION

The TC2117 is a precision, positive output LDO. Unlike bipolar regulators, the TC2117 supply current does not increase proportionally with load current. In addition,  $V_{OUT}$  remains stable and within regulation over the entire 0 mA to 800 mA operating load range.



**FIGURE 4-1:** Typical Application Circuit.

### 4.1 Output Capacitor

A 1  $\mu\text{F}$  (min) capacitor from  $V_{OUT}$  to ground is required. The output capacitor should have an effective series resistance of 0.2 $\Omega$  to 10 $\Omega$ . A 1  $\mu\text{F}$  capacitor should be connected from  $V_{IN}$  to GND if there is more than 10 inches of wire between the regulator and the AC filter capacitor, or if a battery is used as the power source. Aluminum electrolytic or tantalum capacitor types can be used. (Since many aluminum electrolytic capacitors freeze at approximately -30°C, solid tantalums are recommended for applications operating below -25°C.) When operating from sources other than batteries, supply noise rejection and transient response can be improved by increasing the value of the input and output capacitors and employing passive filtering techniques.

## 4.2 Thermal Considerations

### 4.2.1 THERMAL SHUTDOWN

Integrated thermal protection circuitry shuts the regulator off when die temperature exceeds 160°C. The regulator remains off until the die temperature drops to approximately 150°C.

### 4.2.2 POWER DISSIPATION

The amount of power the regulator dissipates is primarily a function of input and output voltage, and output current. The following equation is used to calculate the worst-case actual power dissipation:

#### EQUATION 4-1:

$$P_D = (V_{INMAX} - V_{OUTMIN})I_{LOADMAX}$$

Where:

- $P_D$  = Worst-case actual power dissipation
- $V_{INMAX}$  = Maximum voltage on  $V_{IN}$
- $V_{OUTMIN}$  = Minimum regulator output voltage
- $I_{LOADMAX}$  = Maximum output (load) current

The maximum *allowable* power dissipation (Equation 4-2) is a function of the maximum ambient temperature ( $T_{AMAX}$ ), the maximum allowable die temperature (+125°C) and the thermal resistance from junction-to-air ( $\theta_{JA}$ ).

#### EQUATION 4-2:

$$P_{DMAX} = \frac{(T_{JMAX} - T_{AMAX})}{\theta_{JA}}$$

Where all terms are previously defined.

Table 4-2 shows various values of  $\theta_{JA}$  for the TC2117 mounted on a 1/16 inch, 2-layer PCB with 1 oz. copper foil.

**TABLE 4-2: THERMAL RESISTANCE GUIDELINES FOR TC2117 IN 3-PIN SOT-223 PACKAGE**

Copper Area (Topside)*	Copper Area (Backside)	Board Area	Thermal Resistance
2500 sq mm	2500 sq mm	2500 sq mm	45°C/W
1000 sq mm	2500 sq mm	2500 sq mm	45°C/W
225 sq mm	2500 sq mm	2500 sq mm	53°C/W
100 sq mm	2500 sq mm	2500 sq mm	59°C/W
1000 sq mm	1000 sq mm	1000 sq mm	52°C/W
1000 sq mm	0 sq mm	1000 sq mm	55°C/W

\* Tab of device attached to topside copper.

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**TABLE 4-3: THERMAL RESISTANCE GUIDELINES FOR TC2117 IN 3-PIN DDPK PACKAGE**

Copper Area (Topside)*	Copper Area (Backside)	Board Area	Thermal Resistance ( $\theta_{JA}$ )
2500 sq mm	2500 sq mm	2500 sq mm	25°C/W
1000 sq mm	2500 sq mm	2500 sq mm	27°C/W
125 sq mm	2500 sq mm	2500 sq mm	35°C/W

\*Tab of device attached to topside copper.

Equation 4-1 can be used in conjunction with Equation 4-2 to ensure regulator thermal operation is within limits. For example:

Given:

$$\begin{aligned}V_{INMAX} &= 5.0V \pm 5\% \\V_{OUTMIN} &= 3.3V \pm 0.5\% \\I_{LOADMAX} &= 400 \text{ mA} \\T_{JMAX} &= 125^\circ\text{C} \\T_{AMAX} &= 55^\circ\text{C} \\\theta_{JA} &= 59^\circ\text{C/W (SOT-223)}\end{aligned}$$

Find: 1. Actual power dissipation  
2. Maximum allowable dissipation

Actual power dissipation:

$$\begin{aligned}P_D &\approx (V_{INMAX} - V_{OUTMIN})I_{LOADMAX} \\&= [(5.0 \times 1.05) - (3.3 \times .995)] 400 \times 10^{-3} \\&= 786 \text{ mW}\end{aligned}$$

Maximum allowable power dissipation:

$$\begin{aligned}P_{DMAX} &= \frac{(T_{JMAX} - T_{AMAX})}{\theta_{JA}} \\&= \frac{(125 - 55)}{59} \\&= 1.186\text{W}\end{aligned}$$

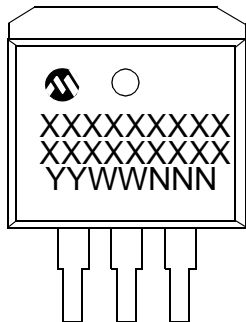
In this example, the TC2117 dissipates a maximum of only 786 mW, which is below the allowable limit of 1.186W. In a similar manner, Equation 4-1 and Equation 4-2 can be used to calculate the maximum current and/or input voltage limits.



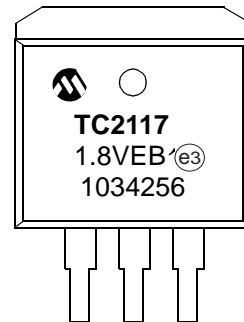
## 5.0 PACKAGING INFORMATION

### 5.1 Package Marking Information

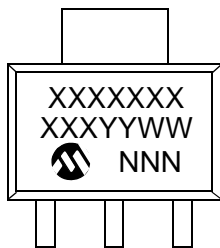
3-Lead DDPAK



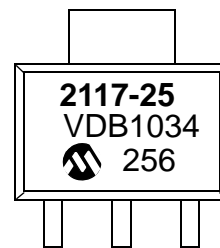
Example



3-Lead SOT-223



Example



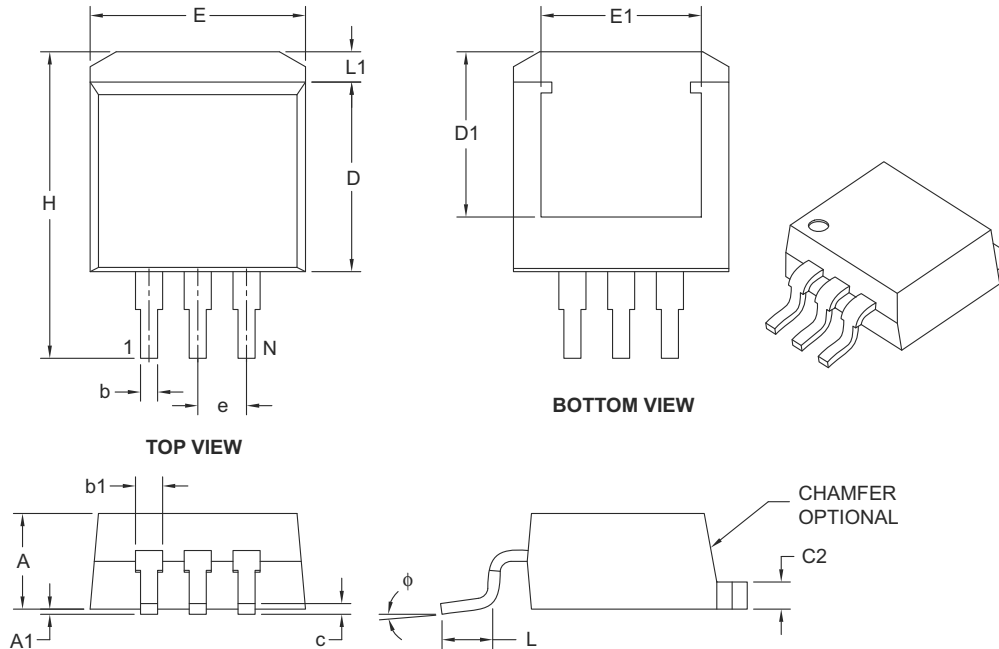
<b>Legend:</b>	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

**Note:** In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

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## 3-Lead Plastic (EB) [DDPAK]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension Limits	Units	INCHES		
		MIN	NOM	MAX
Number of Pins	N	3		
Pitch	e	.100 BSC		
Overall Height	A	.160	–	.190
Standoff §	A1	.000	–	.010
Overall Width	E	.380	–	.420
Exposed Pad Width	E1	.245	–	–
Molded Package Length	D	.330	–	.380
Overall Length	H	.549	–	.625
Exposed Pad Length	D1	.270	–	–
Lead Thickness	c	.014	–	.029
Pad Thickness	C2	.045	–	.065
Lower Lead Width	b	.020	–	.039
Upper Lead Width	b1	.045	–	.070
Foot Length	L	.068	–	.110
Pad Length	L1	–	–	.067
Foot Angle	$\phi$	0°	–	8°

**Notes:**

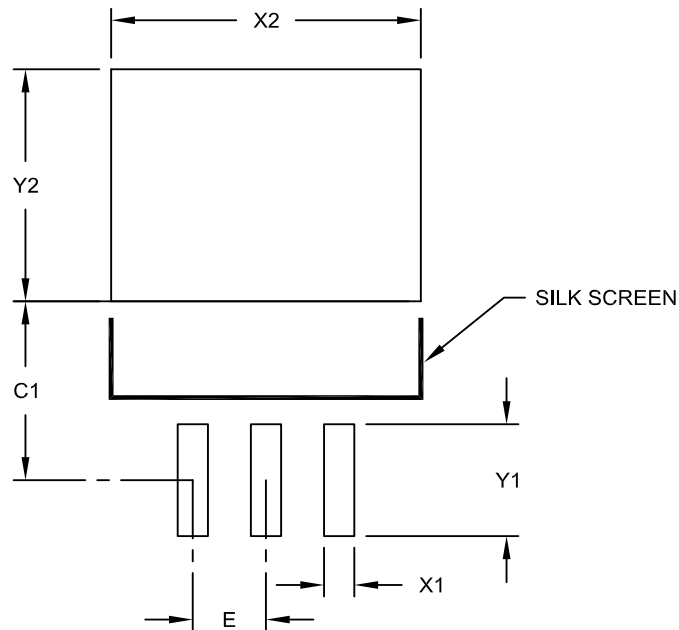
- § Significant Characteristic.
- Dimensions D and E do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" per side.
- Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-011B

## 3-Lead Plastic (EB) [DDPAK]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Dimension Limits	Units	INCHES		
		MIN	NOM	MAX
Contact Pitch	E	.100 BSC		
Pad Width	X2			.423
Pad Length	Y2			.327
Contact Pad Spacing	C1		.252	
Contact Pad Width (X3)	X1			.041
Contact Pad Length (X3)	Y1			.157

**Notes:**

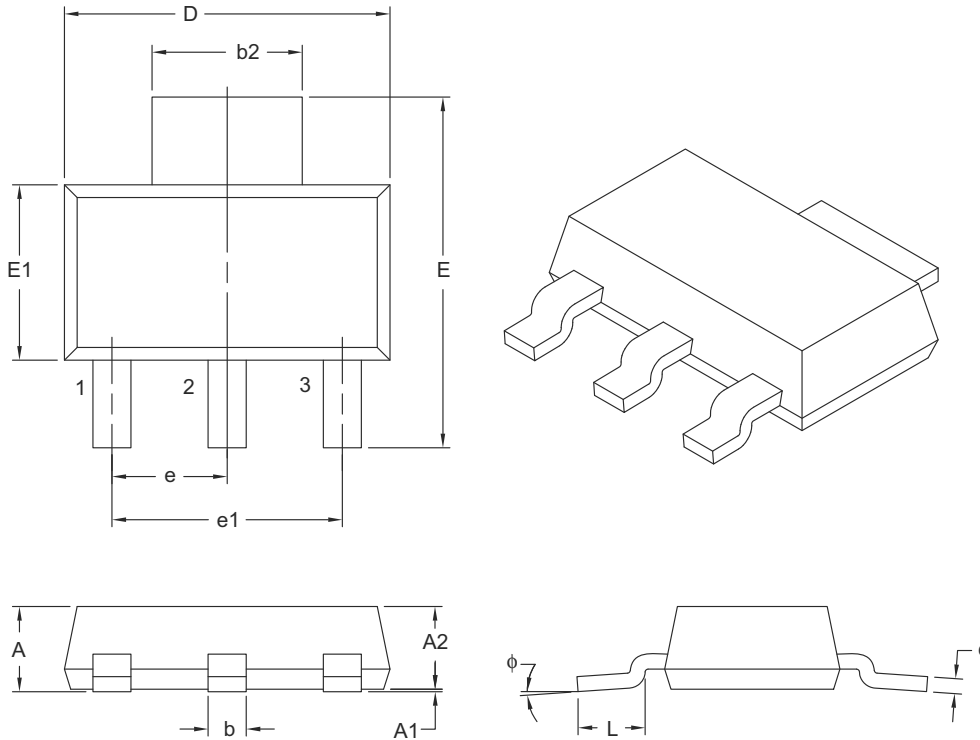
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2011A

## 3-Lead Plastic Small Outline Transistor (DB) [SOT-223]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension Limits	Units	MILLIMETERS		
		MIN	NOM	MAX
Number of Leads	N	3		
Lead Pitch	e	2.30 BSC		
Outside Lead Pitch	e1	4.60 BSC		
Overall Height	A	–	–	1.80
Standoff	A1	0.02	–	0.10
Molded Package Height	A2	1.50	1.60	1.70
Overall Width	E	6.70	7.00	7.30
Molded Package Width	E1	3.30	3.50	3.70
Overall Length	D	6.30	6.50	6.70
Lead Thickness	c	0.23	0.30	0.35
Lead Width	b	0.60	0.76	0.84
Tab Lead Width	b2	2.90	3.00	3.10
Foot Length	L	0.75	–	–
Lead Angle	$\phi$	0°	–	10°

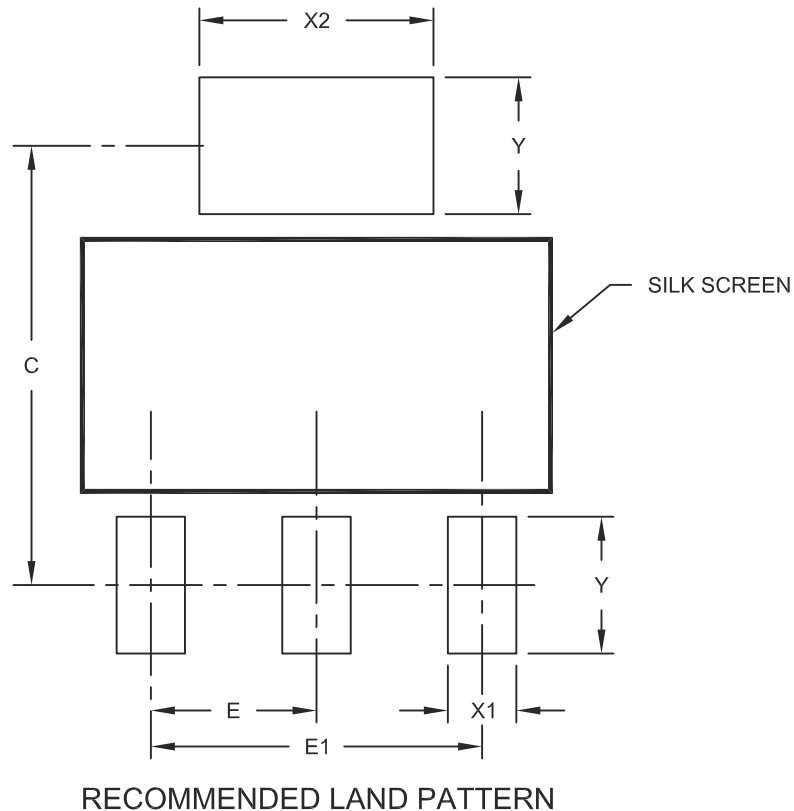
**Notes:**

- Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.
- Dimensioning and tolerancing per ASME Y14.5M.  
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-032B

## 3-Lead Plastic Small Outline Transistor (DB) [SOT-223]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension Limits	Units	MILLIMETERS		
		MIN	NOM	MAX
Contact Pitch	E		2.30 BSC	
Overall Pitch	E1		4.60 BSC	
Contact Pad Spacing	C		6.10	
Contact Pad Width	X1			0.95
Contact Pad Width	X2			3.25
Contact Pad Length	Y			1.90

**Notes:**

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2032A

# TC2117

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NOTES:

## APPENDIX A: REVISION HISTORY

### Revision D (September 2010)

The following is the list of modifications:

1. Updated [Figure 2-4](#).
2. Updated package drawings (C04-011B, C04-2011A, C04-032B, C04-2032A).

### Revision C (October 2006)

The following is the list of modifications:

1. **Section 1.0 “Electrical Characteristics”**: Changed dropout voltage typical value for  $I_L = 500$  mA from 700 to 1000 and maximum value from 1000 to 1200 for. Changed typical value for  $I_L = 800$  mA from 890 to 1200.
2. **Section 5.0 “Packaging information”**: Added package marking information and package outline drawings.
3. Added disclaimer to package outline drawings.
4. Added Appendix A Revision History.

### Revision B (May 2002)

- Undocumented Changes.

### Revision A (May 2001)

- Original Release of this Document.

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NOTES:



## PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	<u>X.XX</u>	<u>XX</u>	<u>XX</u>
Device	Voltage Option	Package	Tape and Reel
Device	TC2117 Fixed Output CMOS LDO Positive Regulator		
Voltage Option:*	1.8V = 1.8V 2.5V = 2.5V 3.0V = 3.0V 3.3V = 3.3V * Other output voltages are available. Please contact your local Microchip sales office for details.		
Package	DB = Plastic (SOT-223), 3-lead DBTR = Plastic (SOT-223), 3-lead, Tape and Reel EB = Plastic Transistor Outline (DDPAK), 3-Lead EBTR = Plastic Transistor Outline (DDPAK), 3-Lead, Tape and Reel		
<b>Examples:</b>			
a)	TC2117-1.8VEBTR	1.8V LDO, DDPAK-3 pkg., Tape and Reel	
b)	TC2117-2.5VEBTR	2.5V LDO, DDPAK-3 pkg., Tape and Reel	
c)	TC2117-3.0VEBTR	3.0V LDO, DDPAK-3 pkg., Tape and Reel	
d)	TC2117-3.3VEBTR	3.3V LDO, DDPAK-3 pkg., Tape and Reel	
a)	TC2117-1.8VDB	1.8V LDO, SOT-223 pkg.	
b)	TC2117-1.8VDBTR	1.8V LDO, SOT-223 pkg., Tape and Reel	
c)	TC2117-2.5VDB	2.5V LDO, SOT-223 pkg.	
d)	TC2117-2.5VDBTR	2.5V LDO, SOT-223 pkg., Tape and Reel	
e)	TC2117-3.0VDB	3.0V LDO, SOT-223 pkg.	
f)	TC2117-3.0VDBTR	3.0V LDO, SOT-223 pkg., Tape and Reel	
g)	TC2117-3.3VDB	3.3V LDO, SOT-223 pkg.	
h)	TC2117-3.3VDBTR	3.3V LDO, SOT-223 pkg., Tape and Reel	

# TC2117

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NOTES:

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**Note the following details of the code protection feature on Microchip devices:**

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
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